μESD3.3DT5G SERIES

ESD Protection Diodes

Ultra Small SOT-723 Package

The μ ESD Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications.

Specification Features:

- Small Body Outline Dimensions: 0.047" x 0.032" (1.20 mm x 0.80 mm)
- Low Body Height: 0.020" (0.5 mm)
- Stand-off Voltage: 3.3 V 6.0 V
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- IEC61000-4-4 Level 4 EFT Protection
- AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic Epoxy Meets UL 94 V–0 **LEAD FINISH:** 100% Matte Sn (Tin) **MOUNTING POSITION:** Any

QUALIFIED MAX REFLOW TEMPERATURE: $260^\circ\mathrm{C}$

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000–4–2 (ESD) Air Contact		±30 ±30	kV
IEC 61000-4-4 (EFT)		40	А
ESD Voltage Per Human Body Model Per Machine Model		16 400	kV V
Total Power Dissipation on FR-5 Board (Note 1) @ T _A = 25°C Derate above 25°C Thermal Resistance Junction-to-Ambient	Ρ _D R _{θJA}	240 1.9 525	mW mW/°C °C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	ΤL	260	°C

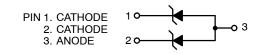
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.



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ت xx = D

= Device Code = Date Code

M = Date Code

ORDERING INFORMATION

SOT-723

CASE 631AA

STYLE 4

Device	Package	Shipping [†]
UESDxxDT5G	SOT-723	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

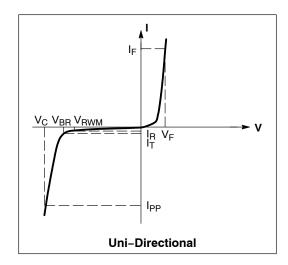
See specific marking information in the device marking column of the table on page 2 of this data sheet.

μESD3.3DT5G SERIES

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ I _{PP}		
V _{RWM}	Working Peak Reverse Voltage		
I _R	Maximum Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
Ι _Τ	Test Current		
١ _F	Forward Current		
V _F	Forward Voltage @ I _F		
P _{pk}	Peak Power Dissipation		
Ċ	Max. Capacitance $@V_R = 0$ and f = 1 MHz		



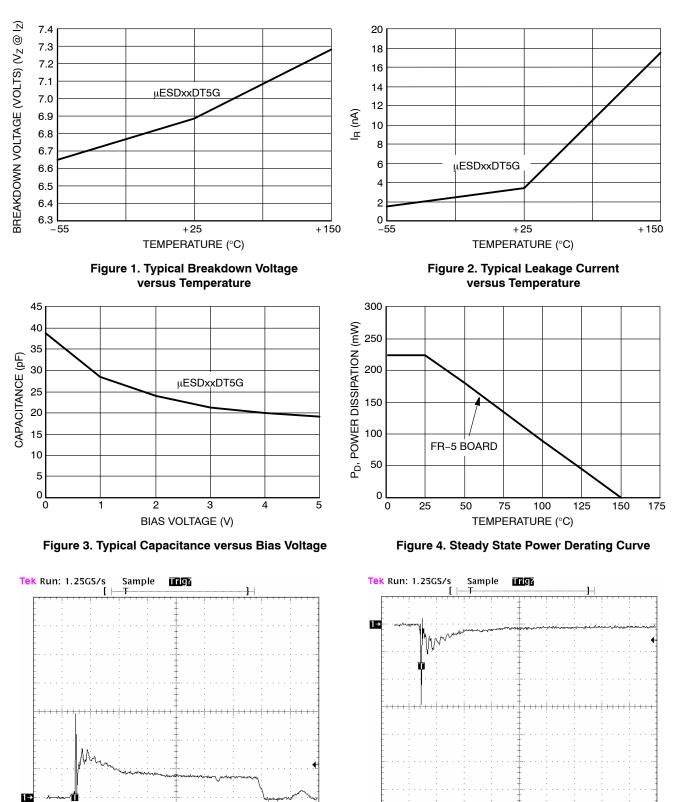
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 1.1 V Max. @ I_F = 10 mA for all types)

	Device	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	Ι _Τ	C (pF)
Device*	Marking	Мах	Мах	Min	mA	Тур
UESD3.3DT5G	L0	3.3	1.0	5.0	1.0	47
UESD5.0DT5G	L2	5.0	0.1	6.2	1.0	38
UESD6.0DT5G	L3	6.0	0.1	7.0	1.0	34

*Other voltages available upon request. 2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.

μESD3.3DT5G SERIES

TYPICAL CHARACTERISTICS





M 40.0ns Ch1 J

-5.8 V

11.2 V

M 40.0ns Ch1 J

Figure 5. Positive 8 kV contact per IEC 6100-4-2

- µESD5.0DT5G

C1 10.0 VΩ

C1% 10.0 VΩ



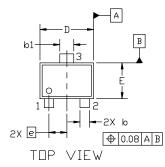


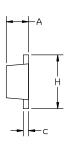
SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

NDTES:

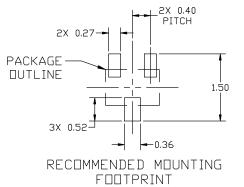
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS. 1.
- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



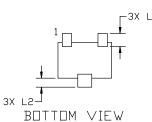


SIDE VIEW

		MILLIMETERS			
	DIM	MIN.	NDM.	MAX.	
1	А	0.45	0.50	0.55	
	b	0.15	0.21	0.27	
	b1	0.25	0.31	0.37	
	С	0.07	0.12	0.17	
	D	1.15	1.20	1.25	
	E	0.75	0.80	0.85	
	e	0.40 BSC			
	Н	1.15	1.20	1.25	
	L	0.29 REF			
	L2	0.15	0.20	0.25	



*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

2. EMITTER 2.	II: STYLE 3: ANODE PIN 1. ANODE N/C 2. ANODE CATHODE 3. CATHODE	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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DESCRIPTION:	SOT-723 1.20x0.80x	0.50, 0.40P			PAGE 1 OF 1

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